

NCE N-Channel Super Trench Power MOSFET



The NCEP0218K uses **Super Trench** technology that is uniquely optimized to provide the most efficient high frequency switching performance. Both conduction and switching power losses are minimized due to an extremely low combination of $R_{DS(ON)}$ and Q_g . This device is ideal for high-frequency switching and synchronous rectification.

General Features

• V_{DS} =200V,I_D =18A

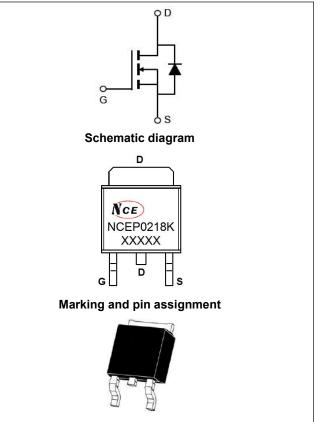
 $R_{DS(ON)}$ =145m Ω (typical) @ V_{GS}=10V

- Excellent gate charge x R_{DS(on)} product(FOM)
- Very low on-resistance R_{DS(on)}
- 175 °C operating temperature
- Pb-free lead plating

Application

- LED backlighting
- Ideal for high-frequency switching and synchronous rectification

100% UIS TESTED! 100% ΔVds TESTED!



TO-252 -2Ltop view

Package Marking and Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|-----------|----------------|-----------|------------|----------|
| NCEP0218K | NCEP0218K | TO-252 | - | - | - |

Absolute Maximum Ratings (T_A=25℃ unless otherwise noted)

| Parameter | Symbol | Limit | Unit | |
|--|-----------------|------------|------|--|
| Drain-Source Voltage | V _{DS} | 200 | V | |
| Gate-Source Voltage | V _{GS} | ±20 | V | |
| Drain Current-Continuous | ID | 18 | A | |
| Drain Current-Continuous(Tc=100 ℃) | l₀(100℃) | 12 | A | |
| Pulsed Drain Current | Ідм | 72 | A | |
| Maximum Power Dissipation | PD | 140 | W | |
| Derating factor | | 0.93 | W/°C | |
| Single pulse avalanche energy (Note 1) | E _{AS} | 80 | mJ | |
| Operating Junction and Storage Temperature Range | TJ,TSTG | -55 To 175 | °C | |

Thermal Characteristic

| Thermal Résistance, Junction-to-Case | R _{eJC} | 1.07 | °C/W | |
|--------------------------------------|------------------|------|------|--|
|--------------------------------------|------------------|------|------|--|



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Electrical Characteristics (T_A=25 $^{\circ}$ C unless otherwise noted)

| Parameter | Symbol | Condition | Min | Тур | Мах | Unit |
|------------------------------------|---------------------|---|-----|-----|------|------|
| Off Characteristics | · · | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =250µA | 200 | - | - | V |
| Zero Gate Voltage Drain Current | IDSS | V _{DS} =200V,V _{GS} =0V | - | - | 1 | μA |
| Gate-Body Leakage Current | I _{GSS} | V_{GS} =±20V, V_{DS} =0V | - | - | ±100 | nA |
| On Characteristics | ···· | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} ,I _D =250µA | 2.5 | 3.5 | 4.5 | V |
| Drain-Source On-State Resistance | R _{DS(ON)} | V_{GS} =10V, I _D =9A | - | 145 | 155 | mΩ |
| Forward Transconductance | G FS | V _{DS} =5V,I _D =18A | 15 | - | - | S |
| Dynamic Characteristics | | | | | | |
| Input Capacitance | Cliss | | - | 483 | | PF |
| Output Capacitance | Coss | V_{DS} =100V, V_{GS} =0V, | - | 42 | | PF |
| Reverse Transfer Capacitance | Crss | F=1.0MHz | - | 1 | | PF |
| Switching Characteristics (Note 2) | · · | | | | | |
| Turn-on Delay Time | t _{d(on)} | | - | 4 | - | nS |
| Turn-on Rise Time | tr | V _{DD} =100V, RL=8Ω | - | 5 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | V_{GS} =10V, R_{G} =3 Ω | - | 10 | - | nS |
| Turn-Off Fall Time | tr | | - | 2 | - | nS |
| Total Gate Charge | Qg | N/ 400\/\ 40A | - | 9.2 | - | nC |
| Gate-Source Charge | Q _{gs} | V_{DS} =100V,I _D =18A, | - | 3.8 | - | nC |
| Gate-Drain Charge | Q _{gd} | V _{GS} =10V | - | 2.3 | - | nC |
| Drain-Source Diode Characteristics | | | | | | |
| Diode Forward Voltage | V _{SD} | V _{GS} =0V,I _S =18A | - | - | 1.2 | V |
| Diode Forward Current | Is | | - | - | 18 | А |
| Reverse Recovery Time | t _{rr} | T _J = 25°C, I _F =18A | - | 25 | - | nS |
| Reverse Recovery Charge | Qrr | di/dt = 100A/µs | - | 110 | - | nC |

Notes:

1. EAS condition : Tj=25 $^\circ \!\! \mathbb{C}$,V_{DD}=50V,V_G=10V,L=0.5mH,Rg=25\Omega

2. Guaranteed by design, not subject to production

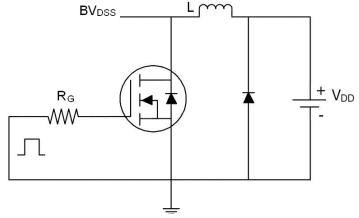
3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsin k, assuming a maximum junction temperature of TJ(MAX)=175° C. The SOA curve provides a single pulse rating.



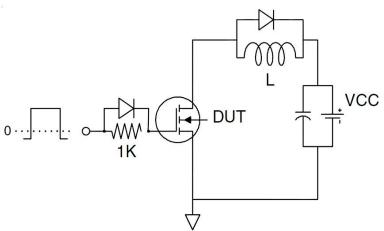
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Test Circuit

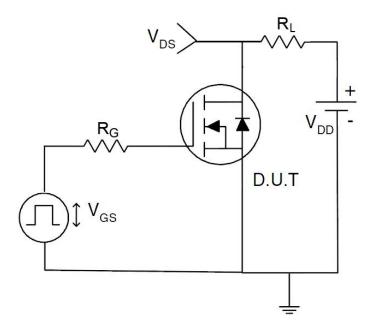
1) E_{AS} test Circuit



2) Gate charge test Circuit

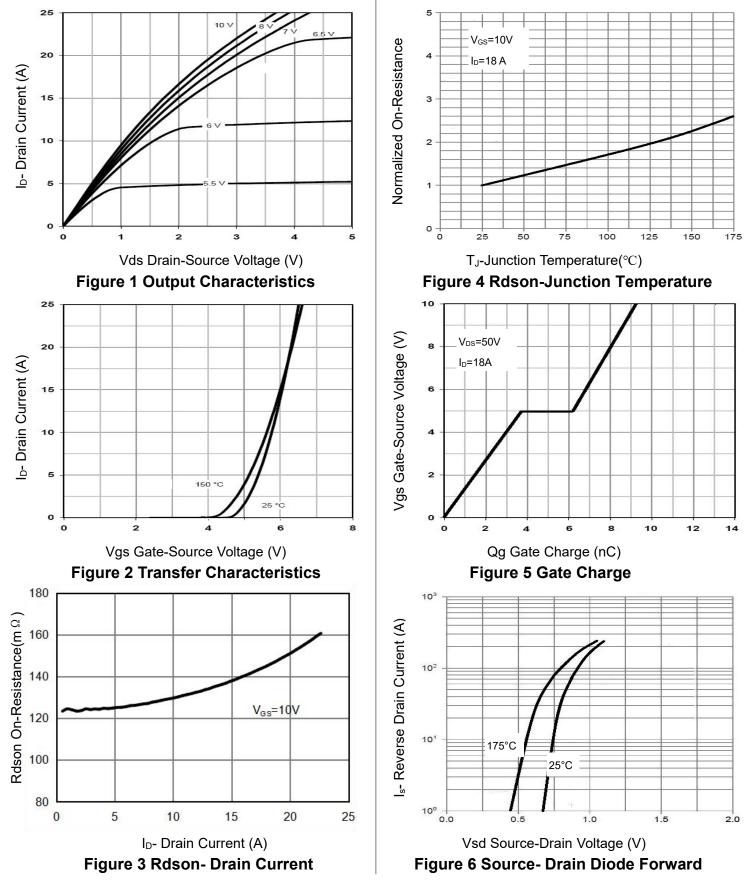


3) Switch Time Test Circuit





Typical Electrical and Thermal Characteristics





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NCEP0218K

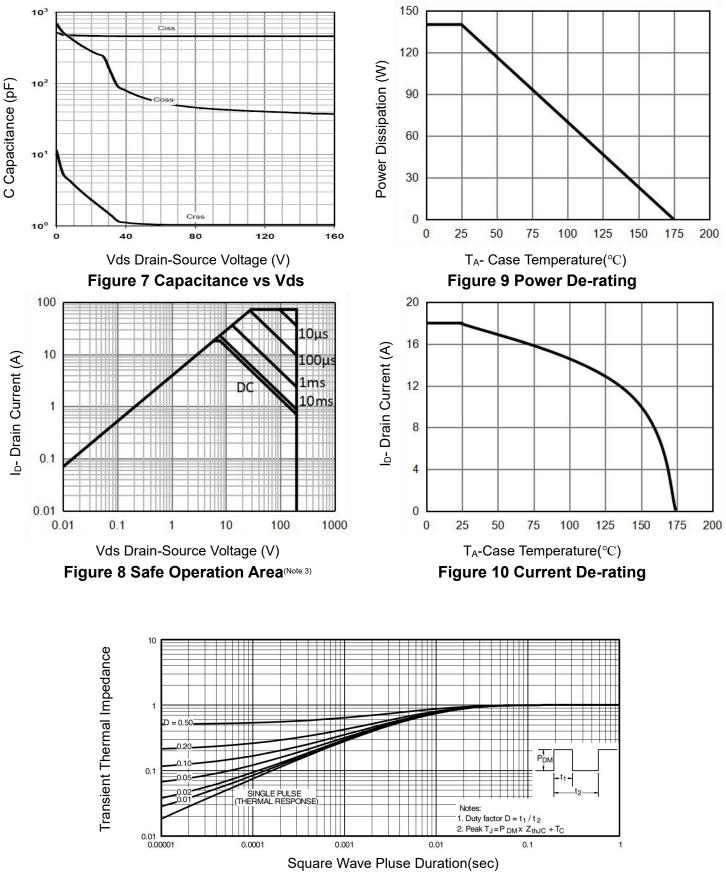
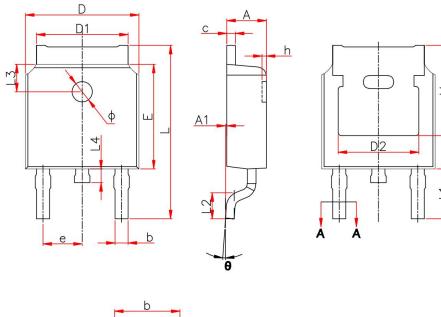
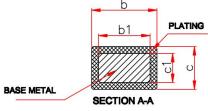


Figure 11 Normalized Maximum Transient Thermal Impedance



TO-252-2L Package Information





| Symbol | Millimeters | | | |
|--------|-------------|-------|--|--|
| Symbol | Min. | Max. | | |
| Α | 2.20 | 2.40 | | |
| A1 | 0.00 | 0.13 | | |
| b | 0.66 | 0.86 | | |
| b1 | 0.73 | 0.79 | | |
| C | 0.46 | 0.58 | | |
| c1 | 0.50 | 0.52 | | |
| D | 6.50 | 6.70 | | |
| D1 | 5.10 | 5.46 | | |
| D2 | 4.83 REF. | | | |
| E | 6.00 | 6.20 | | |
| е | 2.19 | 2.39 | | |
| L | 9.80 | 10.40 | | |
| L1 | 2.90 REF. | | | |
| L2 | 1.40 | 1.70 | | |
| L3 | 1.60 REF. | | | |
| L4 | 0.60 | 1.00 | | |
| φ | 1.10 | 1.30 | | |
| θ | 0° | 8° | | |



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